

HA17555 Series

Precision Timer

REJ03D0681-0100 (Previous: ADE-204-064)

> Rev.1.00 Jun 15, 2005

Description

HA17555 Series are ICs designed for accurate time delays or oscillations. It provides both of trigger terminal and reset terminal in order to enable a wide scope of application including Mono Multi Vibrator and Astable Multi Vibrator, and the number of external components is fewer. Further, it's compatible with NE555 of singnetics.

Features

- Mono multi vibrator can be constructed with one resistor and one capacitor.
- Astable multi vibrator can be constructed with two resistors and one capacitor.
- Delay time can be established widely from several μ seconds to several hours.
- Pulse Duty can be controlled.
- The maximum value of both sink current and source current is 200mA.
- Direct connection of output to TTL is possible.
- Temperature/delay time ratio is 50 ppm/°C (typ).
- Output is normally in the on and off states.

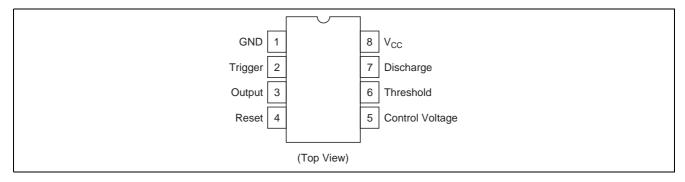
Ordering Information

| Application | Type No. | Package Code (Previous Code) |
|----------------|-----------|------------------------------|
| Industrial use | HA17555PS | PRDP0008AF-A (DP-8B) |
| | HA17555FP | PRSP0008DE-B (FP-8DGV) |
| Commercial use | HA17555 | PRDP0008AF-A (DP-8B) |
| | HA17555F | PRSP0008DE-B (FP-8DGV) |

Applications

- Delay Time Generator (Mono Multi Vibrator)
- Pulse Generator (Astable Multi Vibrator)
- Pulse Width Modulator
- Pulse Location Modulator
- Miss Pulse Detector

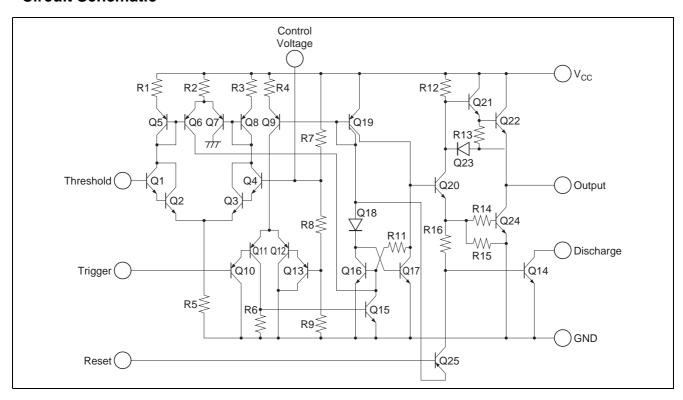
Pin Arrangement



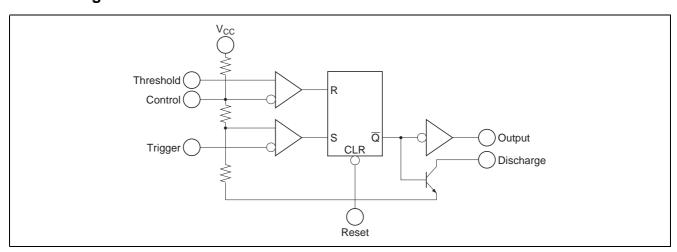
Pin Description

| Pin No. | Function | |
|---------------------|---------------------|--|
| www.DataSheet4U.com | Ground pin | |
| 2 | Trigger pin | |
| 3 | Output pin | |
| 4 | Reset pin | |
| 5 | Control voltage pin | |
| 6 | Threshold pin | |
| 7 | Discharge pin | |
| 8 | V _{CC} pin | |

Circuit Schematic



Block Diagram



Absolute Maximum Ratings

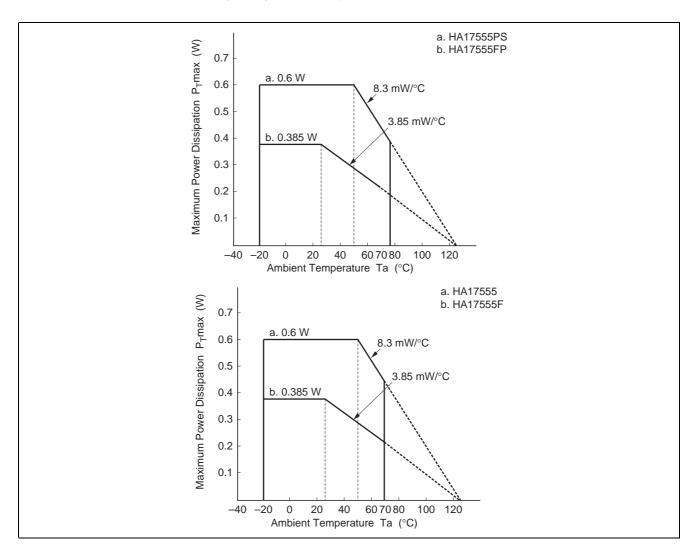
 $(Ta = 25^{\circ}C)$

| Item | Symbol | HA17555PS/FP | HA17555/F | Unit |
|-----------------------|-----------------|--------------|-------------|------|
| Supply voltage | V _{CC} | 18 | 18 | V |
| Discharge current | I _T | 200 | 200 | mA |
| Output source current | Isource | 200 | 200 | mA |
| Output sink current | Isink | 200 | 200 | mA |
| Power dissipation*1 | P _T | 600/385 | 600/385 | mW |
| Operating temperature | Topr | –20 to +75 | -20 to +70 | °C |
| Storage temperature | Tstg | -55 to +125 | -55 to +125 | °C |

Note: 1. For the HA17555/PS,

This value applies up to Ta = 50° C; at temperatures above this, $8.3 \text{mW}/^{\circ}$ C derating should be applied. For the HA17555F/FP,

This value applies up to Ta = 25°C; at temperatures above this, 3.85mW/°C derating should be applied. See notes on SOP Package Usage in Reliability section.



Electrical Characteristics

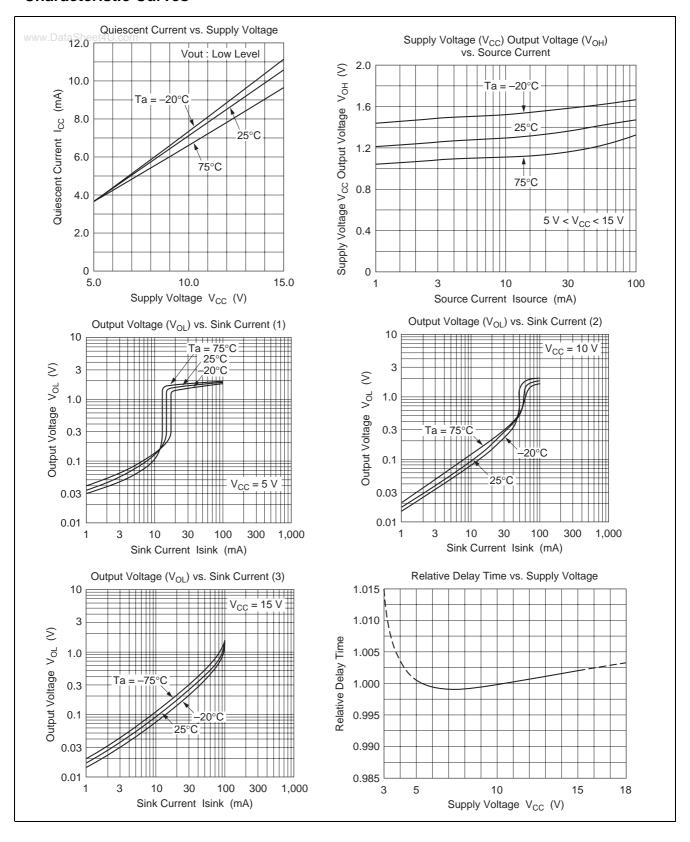
 $(V_{CC} = 5 \text{ to } 15 \text{ V}, Ta = 25^{\circ}C)$

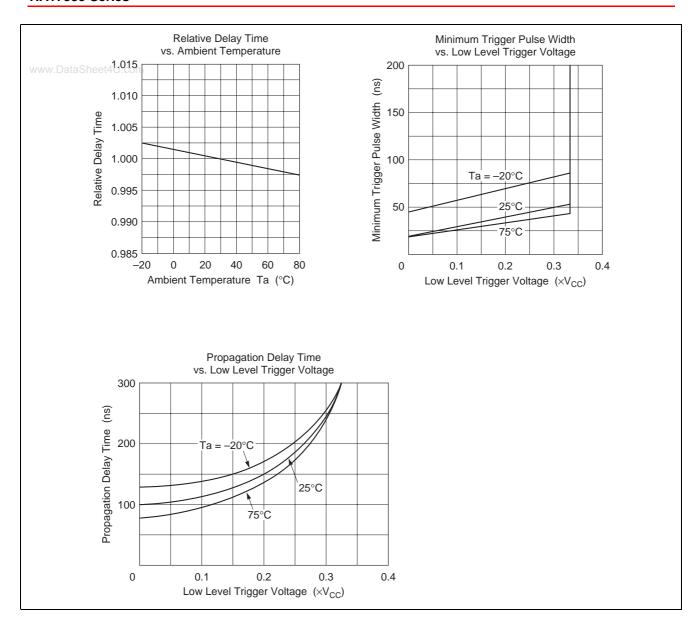
| Item | Symbol | Min | Тур | Max | Unit | Test conditions |
|----------------------------|-------------------|-------|------|------|-------------------|--|
| Supply voltage*1 | V _{CC} | 4.5 | _ | 16.0 | V | |
| Supply current | Icc | _ | 3.0 | 6.0 | mA | V _{CC} = 5 V, R _L = ∞ |
| | Icc | _ | 10 | 15 | mA | V _{CC} = 15 V, R _L = ∞ |
| Timing error*2 | Et | _ | 1.0 | _ | % | |
| (Inherent error) | | | | | | |
| Timing error* ² | Et | _ | 50 | _ | ppm/°C | Ta = -20 to + 75°C |
| (Ta dependency) | | | | | | |
| Timing error* ² | Et | _ | 0.01 | _ | %/V | V _{CC} = 5 to 15 V |
| (Voltage dependency) | | | | | | |
| Threshold voltage | Vth | _ | 2/3 | | $V \times V_{CC}$ | |
| Trigger voltage | V _T | _ | 5.0 | 1 | V | V _{CC} = 15 V |
| | V_T | _ | 1.67 | _ | V | V _{CC} = 5 V |
| Trigger current | Ι _Τ | _ | 0.5 | _ | μΑ | |
| Reset voltage | V_R | 0.2 | 0.5 | 1.0 | V | |
| Reset current | I _R | _ | 0.1 | _ | mA | |
| Threshold current | Ith* ³ | _ | 0.1 | 0.25 | μΑ | |
| Control voltage | V_{CL} | 9 | 10 | 11 | V | V _{CC} = 15 V |
| | V _{CL} | 2.6 | 3.33 | 4.0 | V | V _{CC} = 5 V |
| Output voltage | V _{OL} | _ | 0.1 | 0.25 | V | V _{CC} = 15 V, Isink = 10 mA |
| | | _ | 0.4 | 0.75 | V | V _{CC} = 15 V, Isink = 50 mA |
| | | _ | 2.0 | 2.5 | V | V _{CC} = 15 V, Isink = 100 mA |
| | | _ | 2.5 | _ | V | V _{CC} = 15 V, Isink = 200 mA |
| | | _ | 0.25 | 0.35 | V | V _{CC} = 5 V, Isink = 5 mA |
| Output voltage | V _{OH} | _ | 12.5 | _ | V | V _{CC} = 15 V, Isource = 200 mA |
| | | 12.75 | 13.3 | | V | V _{CC} = 15 V, Isource = 100 mA |
| | | 2.75 | 3.3 | | V | V _{CC} = 5 V, Isource = 100 mA |
| Output rise time | t _r | _ | 100 | _ | ns | No loading |
| Output fall time | t _f | _ | 100 | _ | ns | No loading |
| Oscillation pulse width*4 | tw | 10.0 | _ | _ | ns | |

Notes: 1. When output is low (When it is high, I_{CC} is lower by 1 mA typically.)

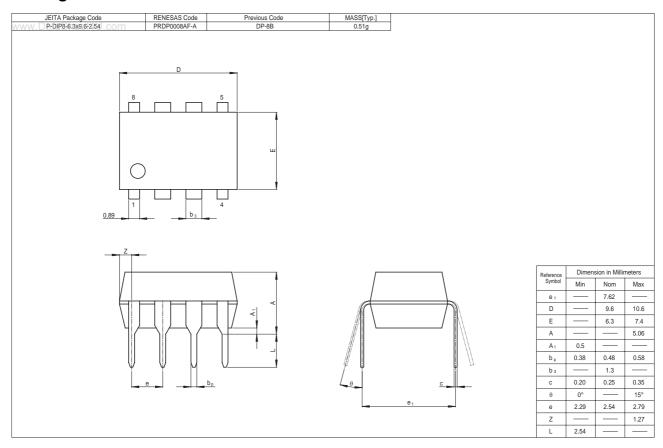
- 2. R_A , R_B = 1 k to 100 k Ω , C = 0.1 μ F, V_{CC} = 5 V or 15 V.
- 3. $(R_A + R_B)$ at V_{CC} = 15 V is determined by the value of lth. It is 20 M Ω Max.
- 4. Output pulse width at mono multi circuit. Output high level pulse width at astable circuit.

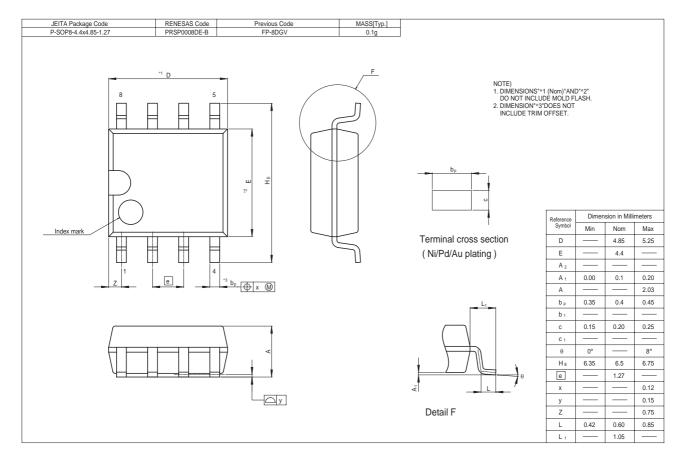
Characteristic Curves





Package Dimensions





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